

## Descriptions

This 80A, 60V N-Channel MOSFET in a TO-252 Plastic Package.

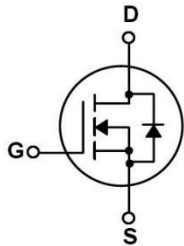
## Features

- Low  $R_{DS(on)}$ ,
- Low gate charge,
- Low  $C_{iss}$ ,
- Fast switching.
- Halogen-free Product.

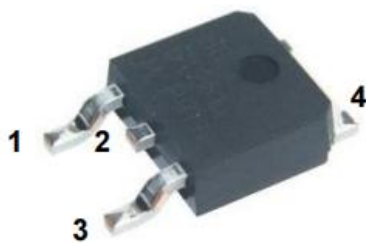
## Applications

- Suited for low voltage applications such as automotive
- DC/DC Converters
- And high efficiency switching for power management in portable and battery operated products.

## Equivalent Circuit



## Pinning



PIN1: Gate    PIN 2: Drain    PIN 3: Source    PIN 4: Drain

## Absolute Maximum Ratings(Ta=25°C)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DSS}$	60	V
Drain Current	$I_D(T_C=25^\circ\text{C})$	80	A
Drain Current	$I_D(T_C=100^\circ\text{C})$	65.6	A
Drain Current - Pulsed	$I_{DM}$	240	A
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Avalanche Energy	$E_{AS}$	215	mJ
Avalanche Current	$I_{AS}$	23.2	A
Power Dissipation	$P_D(T_C=25^\circ\text{C})$	75	W
Junction Temperature Range	$T_j$	150	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-55~150	$^\circ\text{C}$
Maximum Junction-to-Ambient	$t \leq 10\text{s}$	15	$^\circ\text{C/W}$
Maximum Junction-to-Ambient	Steady-State		
Maximum Junction-to-Case	Steady-State	1.6	

## Electrical Characteristics(Ta=25°C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0\text{V}$ $I_D=250\mu\text{A}$	60			V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=60\text{V}$ $V_{GS}=0\text{V}$			1.0	$\mu\text{A}$
		$V_{DS}=48\text{V}$ $T_C=150^\circ\text{C}$			10	
Gate-Body Leakage Current Forward	$I_{GSS}$	$V_{GS}=\pm 20\text{V}$ $V_{DS}=0\text{V}$			$\pm 0.1$	$\mu\text{A}$
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu\text{A}$	1	1.7	2.5	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10\text{V}$ $I_D=60\text{A}$		11	13	m $\Omega$
		$V_{GS}=4.5\text{V}$ $I_D=30\text{A}$		16	20	
Drain-Source Diode Forward Voltage	$V_{SD}$	$V_{GS}=0\text{V}$ $I_S=1\text{A}$		0.67	1.5	V

## Electrical Characteristics(Ta=25°C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Input Capacitance	$C_{iss}$	$V_{DS}=25V \quad V_{GS}=0V$ $f=1.0MHz$		2570		pF
Output Capacitance	$C_{oss}$			152		
Reverse Transfer Capacitance	$C_{rss}$			74		
Gate resistance	$R_g$	$V_{GS}=0V \quad V_{DS}=0V$ $f=1MHz$		1.2		$\Omega$
Total Gate Charge	$Q_g(10V)$	$V_{GS}=-10V \quad V_{DS}=30V$ $I_D=20A$		20.6		nC
Total Gate Charge	$Q_g(4.5V)$			8.5		
Gate Source Charge	$Q_{gs}$			5		
Gate Drain Charge	$Q_{gd}$			2.2		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V \quad V_{DS}=30V$ $R_L=1.5\Omega \quad R_{GEN}=3\Omega$		8.5		ns
Turn-On Rise Time	$t_r$			3.5		
Turn-Off Delay Time	$t_{d(off)}$			27		
Turn-Off Fall Time	$t_f$			3		
Body Diode Reverse Recovery Time	$t_{rr}$	$I_F=20A \quad di/dt=500A/ms$		19		ns
Body Diode Reverse Recovery Charge	$Q_{rr}$	$I_F=20A \quad di/dt=500A/ms$		69.5		nC

Electrical Characteristic Curve

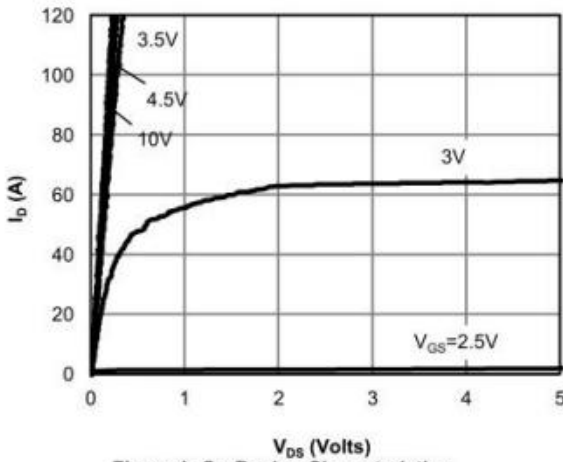


Figure 1: On-Region Characteristics

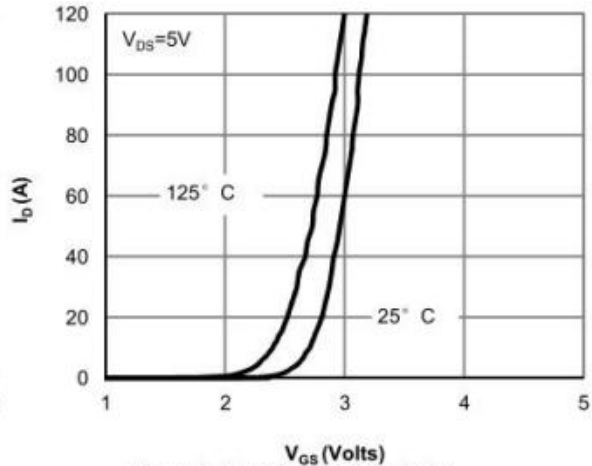


Figure 2: Transfer Characteristics

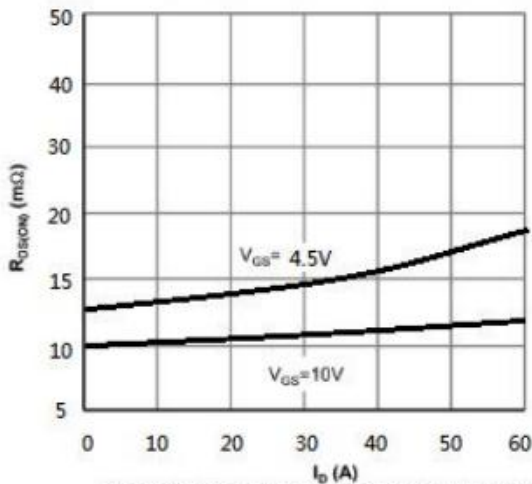


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

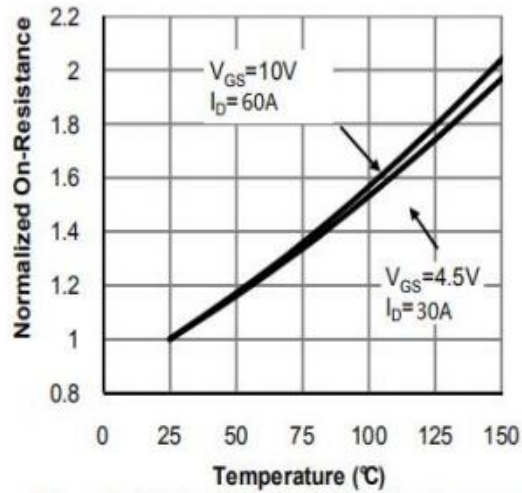


Figure 4: On-Resistance vs. Junction Temperature

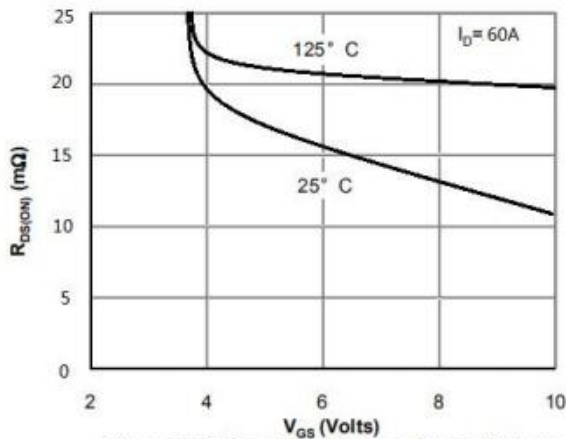


Figure 5: On-Resistance vs. Gate-Source Voltage

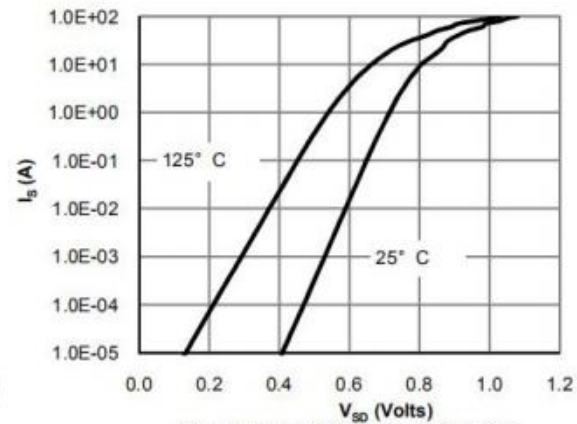


Figure 6: Body-Diode Characteristics

Electrical Characteristic Curve

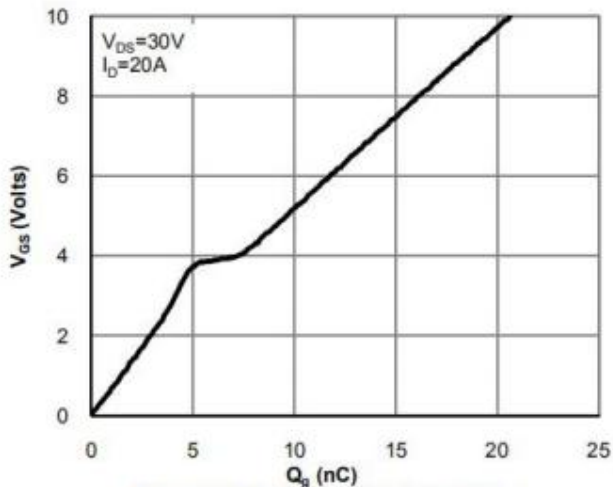


Figure 7: Gate-Charge Characteristics

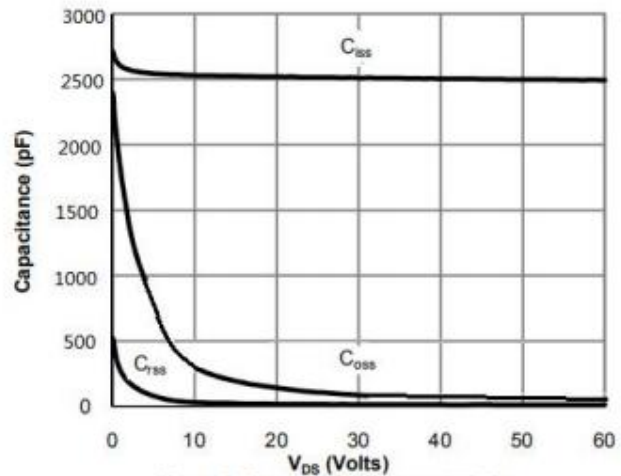


Figure 8: Capacitance Characteristics

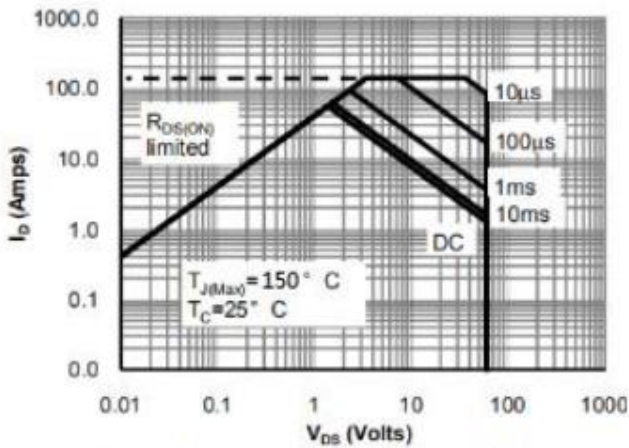


Figure 9: Maximum Forward Biased Safe Operating Area

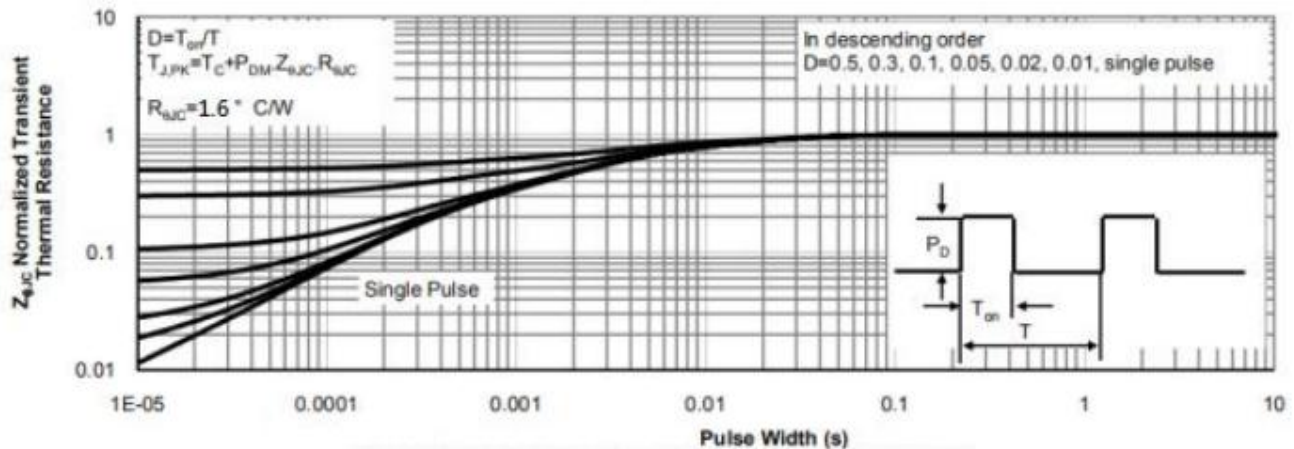


Figure 10: Normalized Maximum Transient Thermal Impedance

**Marking Instructions**



Note:

COT: Company Logo

80N06: Product Type.

\*\*\*\*: Lot No. Code, code change with Lot No.

**Packaging SPEC**

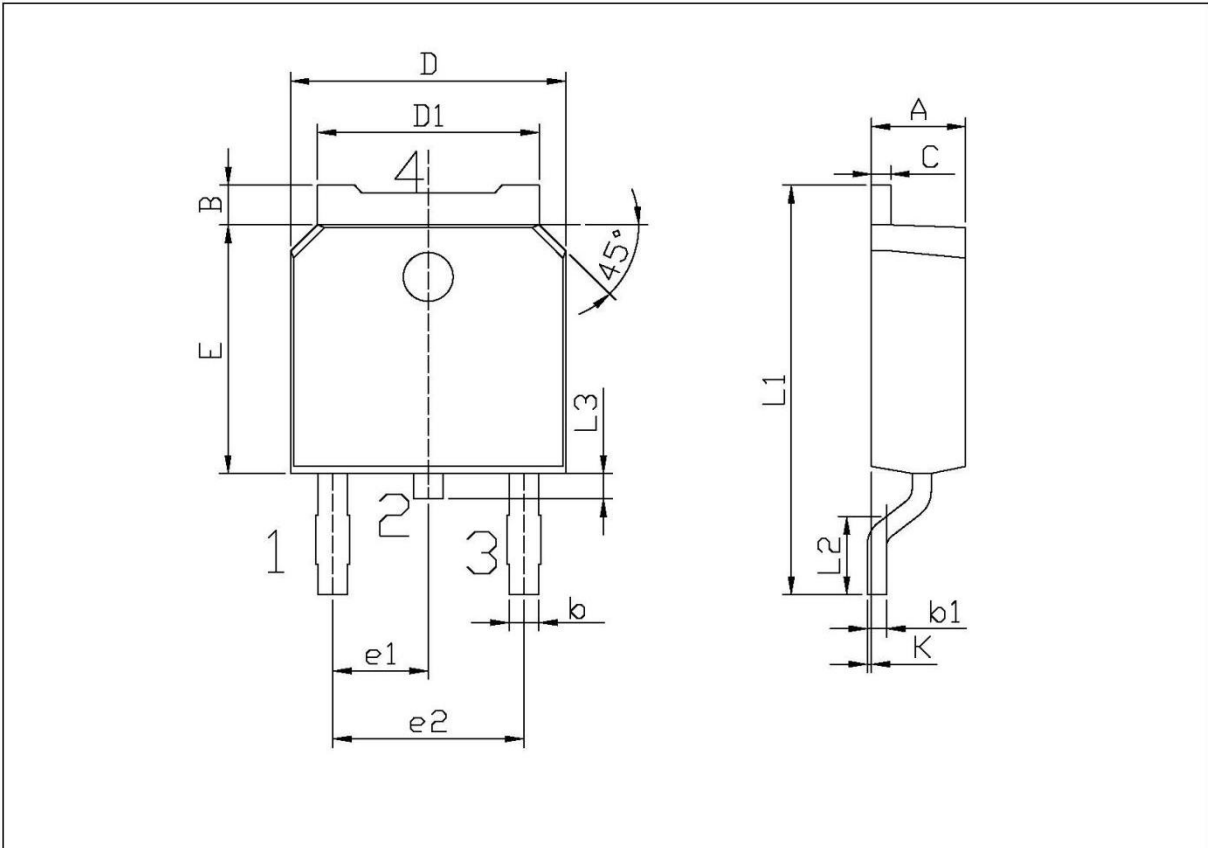
**REEL INFORMATION**

Package Type	Units					Dimension (unit: mm <sup>3</sup> )		
	Units/Reel	Reels/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Reel	Inner Box	Outer Box
TO-252	2,500	2	5,000	6	30,000	13" ×16	360×360×50	380×335×366

**TUBE INFORMATION**

Package Type	Units					Dimension (unit: mm <sup>3</sup> )		
	Units/Tube	Tubes/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Tube	Inner Box	Outer Box
TO-252	75	48	3,600	5	18,000	526×20.5×5.25	555×164×50	575×290×180

Package Outline Dimensions



单位: mm

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
A	2.20	2.40	E	5.95	6.25
B	0.95	1.25	e1	2.24	2.34
b	0.70	0.90	e2	4.43	4.73
b1	0.45	0.55	L1	9.85	10.35
C	0.45	0.55	L2	1.70	2.00
D	6.45	6.75	L3	0.60	0.90
D1	5.10	5.50	K	0.00	0.10

TO-252